# Analog Switch, Dual SPDT, Ultra-Low Resistance

The NLAS4684 is an advanced CMOS analog switch fabricated in Sub–micron silicon gate CMOS technology. The device is a dual Independent Single Pole Double Throw (SPDT) switch featuring Ultra–Low  $R_{ON}$  of 0.5  $\Omega$ , for the Normally Closed (NC) switch, and 0.8  $\Omega$  for the Normally Opened switch (NO) at 2.7 V.

The part also features guaranteed Break Before Make switching, assuring the switches never short the driver.

The NLAS4684 is available in a 2.0 x 1.5 mm bumped die array. The pitch of the solder bumps is 0.5 mm for easy handling.

# **Features**

- Ultra-Low  $R_{ON}$ , < 0.5  $\Omega$  at 2.7 V
- Threshold Adjusted to Function with 1.8 V Control at V<sub>CC</sub> = 2.7–3.3 V
- Single Supply Operation from 1.8–5.5 V
- Tiny 2 x 1.5 mm Bumped Die
- Low Crosstalk, < 83 dB at 100 kHz
- Full 0-V<sub>CC</sub> Signal Handling Capability
- High Isolation, -65 dB at 100 kHz
- Low Standby Current, < 50 nA
- Low Distortion, < 0.14% THD
- R<sub>ON</sub> Flatness of 0.15  $\Omega$
- Pin for Pin Replacement for MAX4684
- High Continuous Current Capability
   ± 300 mA Through Each Switch
- Large Current Clamping Diodes at Analog Inputs ± 300 mA Continuous Current Capability
- Pb-Free Packages are Available

# **Applications**

- Cell Phone
- Speaker Switching
- Power Switching
- Modems
- Automotive



# ON Semiconductor®

http://onsemi.com

# MARKING DIAGRAMS



Microbump-10 CASE 489AA





DFN10 CASE 485C





Micro10 CASE 846B



A = Assembly Location

L = Wafer Lot Y = Year WW, W = Work Week • = Pb-Free Package

(Note: Microdot may be in either location)

#### **FUNCTION TABLE**

IN 1, 2	NO 1, 2	NC 1, 2
0	OFF	ON
1	ON	OFF

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 11 of this data sheet.

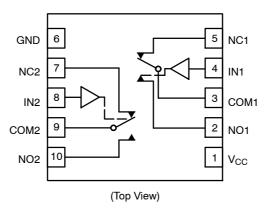


Figure 1. Pin Connections and Logic Diagram (DFN10 and Micro10)

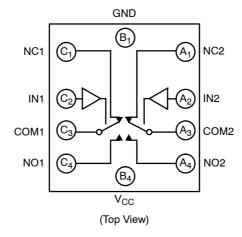


Figure 2. Pin Connections and Logic Diagram (Microbump-10)

# **MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	-0.5 to +7.0	V
V <sub>IS</sub>	Analog Input Voltage (V <sub>NO</sub> , V <sub>NC</sub> , or V <sub>COM</sub> )	$-0.5 \le V_{IS} \le V_{CC} + 0.5$	V
V <sub>IN</sub>	Digital Select Input Voltage	$-0.5 \le V_{  } \le +7.0$	V
I <sub>anl1</sub>	Continuous DC Current from COM to NC/NO	±300	mA
I <sub>anl-pk 1</sub>	Peak Current from COM to NC/NO, 10 duty cycle (Note 1)	±500	mA
I <sub>clmp</sub>	Continuous DC Current into COM/NO/NC	±300	mA
I <sub>clmp 1</sub>	Peak Current into Input Clamp Diodes at COM/NC/NO	±500	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Defined as 10% ON, 90% off duty cycle.

# **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter			Max	Unit
V <sub>CC</sub>	DC Supply Voltage		1.8	5.5	V
V <sub>IN</sub>	Digital Select Input Voltage			5.5	V
V <sub>IS</sub>	Analog Input Voltage (NC, NO, COM)		GND	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature Range		-55	+ 125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Time, SELECT $V_{CC} = 3$ . $V_{CC} = 5$ .	3 V ± 0.3 V 0 V ± 0.5 V	0	100 20	ns/V
ESD	Human Body Model - All Pins			5	kV

# DC CHARACTERISTICS - Digital Section (Voltages Referenced to GND)

				Guaranteed Limit			
Symbol	Parameter	Condition	V <sub>CC</sub> ± 10%	-55°C to 25°C	<85°C	<125°C	Unit
V <sub>IH</sub>	Minimum High-Level Input		2.0	1.4	1.4	1.4	V
	Voltage, Select Inputs		2.5	1.4	1.4	1.4	
	(Figure 9)		3.0	1.4	1.4	1.4	
			5.0	2.0	2.0	2.0	
V <sub>IL</sub>	Maximum Low-Level Input		2.0	0.5	0.5	0.5	V
	Voltage, Select Inputs		2.5	0.5	0.5	0.5	
	(Figure 9)		3.0	0.5	0.5	0.5	
			5.0	0.8	0.8	0.8	
I <sub>IN</sub>	Maximum Input Leakage Current, Select Inputs	V <sub>IN</sub> = 5.5 V or GND	5.5	± 1.0	± 1.0	± 1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or GND	0	±10	±10	±10	μΑ
I <sub>CC</sub>	Maximum Quiescent Supply Current (Note 2)	Select and V <sub>IS</sub> = V <sub>CC</sub> or GND	5.5	± 180	± 200	± 200	nA

<sup>2.</sup> Guaranteed by design.

# DC ELECTRICAL CHARACTERISTICS - Analog Section

					Guarant	teed Ma	ximum	Limit		
				-55°C	to 25°C	<8	5°C	< 12	5°C	
Symbol	Parameter	Condition	V <sub>CC</sub> ± 10%	Min	Max	Min	Max	Min	Max	Unit
R <sub>ON</sub> (NC)	NC "ON" Resistance (Note 3)	$\begin{split} &V_{IN} \leq V_{IL} \\ &V_{IS} = \text{GND to V}_{CC} \\ &I_{IN}I \leq 100 \text{ mA} \end{split}$	2.5 3.0 5.0		0.6 0.5 0.4		0.7 0.5 0.4		0.8 0.5 0.5	Ω
R <sub>ON</sub> (NO)	NO "ON" Resistance (Note 3)	$\begin{split} &V_{IN} \geq V_{IH} \\ &V_{IS} = \text{GND to } V_{CC} \\ &I_{IN}I \leq 100 \text{ mA} \end{split}$	2.5 3.0 5.0		1.0 0.8 0.8		1.0 0.8 0.8		1.0 1.0 0.9	Ω
R <sub>FLAT</sub> (NC)	NC_On-Resistance Flatness (Notes 3, 5)	I <sub>COM</sub> = 100 mA V <sub>IS</sub> = 0 to V <sub>CC</sub>	2.5 3.0 5.0		0.15 0.15 0.15		0.15 0.15 0.15		0.15 0.15 0.15	Ω
R <sub>FLAT (NO)</sub>	NO_On-Resistance Flatness (Notes 3, 5)	I <sub>COM</sub> = 100 mA V <sub>IS</sub> = 0 to V <sub>CC</sub>	2.5 3.0 5.0		0.35 0.35 0.35		0.35 0.35 0.35		0.35 0.35 0.35	Ω
ΔR <sub>ON</sub>	On-Resistance Match Between Channels (Notes 3 and 4)	V <sub>IS</sub> = 1.3 V; I <sub>COM</sub> = 100 mA V <sub>IS</sub> = 1.5 V;	2.5 3.0		0.18 0.06		0.18 0.06		0.18	Ω
		$I_{COM}$ = 100 mA $V_{IS}$ = 2.8 V; $I_{COM}$ = 100 mA	5.0		0.06		0.06		0.06	
I <sub>NC(OFF)</sub> I <sub>NO(OFF)</sub>	NC or NO Off Leakage Current (Figure 13) (Note 3)	$\begin{aligned} V_{IN} &= V_{IL} \text{ or } V_{IH} \\ V_{NO} \text{ or } V_{NC} &= 1.0 \\ V_{COM} &= 4.5 \text{ V} \end{aligned}$	5.5	-1	1	-10	10	-100	100	nA
I <sub>COM(ON)</sub>	COM ON Leakage Current (Figure 13) (Note 3)	$\begin{aligned} &V_{IN} = V_{IL} \text{ or } V_{IH} \\ &V_{NO} \text{ 1.0 V or 4.5 V with} \\ &V_{NC} \text{ floating or} \\ &V_{NC} \text{ 1.0 V or 4.5 V with} \\ &V_{NO} \text{ floating} \\ &V_{COM} = 1.0 \text{ V or 4.5 V} \end{aligned}$	5.5	-2	2	-20	20	-200	200	nA

Guaranteed by design. Resistance measurements do not include test circuit or package resistance.
 ΔR<sub>ON =</sub> R<sub>ON(MAX)</sub> – R<sub>ON(MIN)</sub> between NC1 and NC2 or between NO1 and NO2.
 Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

# AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$ ) (Typical characteristics are at 25°C)

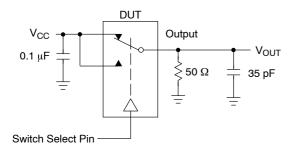
	Guaranteed Maximum Limit				imit							
			v <sub>cc</sub>	V <sub>IS</sub>	- 55	5°C to 2	25°C	<8	5°C	< 12	25°C	
Symbol	Parameter	Test Conditions	(V)	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
t <sub>ON</sub>	Turn-On Time	$R_L = 50 \Omega, C_L = 35 pF$	2.5	1.3			60		70		70	ns
		(Figures 4 and 5)	3.0	1.5			50		60		60	
			5.0	2.8			30		35		35	
t <sub>OFF</sub>	Turn-Off Time	$R_L = 50 \Omega, C_L = 35 pF$	2.5	1.3			50		55		55	ns
		(Figures 4 and 5)	3.0	1.5			40		50		50	
			5.0	2.8			30		35		35	
t <sub>BBM</sub>	Minimum Break-Before-Make Time (Note 6)	$\begin{aligned} &V_{IS}=3.0\\ &R_L=300~\Omega,~C_L=35~pF\\ &(\text{Figure 3}) \end{aligned}$	3.0	1.5	2	15						ns

		Typical @ 25, V <sub>CC</sub> = 5.0 V	
C <sub>NC</sub> Off C <sub>NO</sub> Off C <sub>NC</sub> On C <sub>NO</sub> On	NC Off Capacitance, f = 1 MHz NO Off Capacitance, f = 1 MHz NC On Capacitance, f = 1 MHz NO On Capacitance, f = 1 MHz	102 104 322 330	pF

# ADDITIONAL APPLICATION CHARACTERISTICS (Voltages Referenced to GND Unless Noted)

			v <sub>cc</sub>	Typical	
Symbol	Parameter	Condition	v	25°C	Unit
BW	Maximum On-Channel -3dB Bandwidth or Minimum Frequency Response	$V_{IN}$ = 0 dBm NC $V_{IN}$ centered between $V_{CC}$ and GND (Figure 6) NO	3.0	6.5 9.5	MHz
V <sub>ONL</sub>	Maximum Feed-through On Loss	V <sub>IN</sub> = 0 dBm @ 100 kHz to 50 MHz V <sub>IN</sub> centered between V <sub>CC</sub> and GND (Figure 6)	3.0	-0.05	dB
V <sub>ISO</sub>	Off-Channel Isolation (Note 7)	$f = 100 \text{ kHz}$ ; $V_{IS} = 1 \text{ V RMS}$ ; $C_L = 5 \text{ nF}$ $V_{IN}$ centered between $V_{CC}$ and GND(Figure 6)	3.0	-65	dB
Q	Charge Injection Select Input to Common I/O (Figures 10 and 11)	$V_{IN} = V_{CC \text{ to}} \text{ GND, } R_{IS} = 0 \Omega, C_L = 1 \text{ nF}$ Q = $C_L - \Delta V_{OUT}$ (Figure 7)	3.0	15	рС
THD	Total Harmonic Distortion THD + Noise (Figure 9)	$F_{IS}$ = 20 Hz to 100 kHz, $R_L$ = $R_{gen}$ = 600 $\Omega$ , $C_L$ = 50 pF $V_{IS}$ = 1 V RMS	3.0	0.14	%
VCT	Channel-to-Channel Crosstalk	f = 100 kHz; $V_{IS}$ = 1 V RMS, $C_L$ = 5 pF, $R_L$ = 50 $\Omega$ $V_{IN}$ centered between $V_{CC}$ and GND (Figure 6)	3.0	-83	dB

<sup>6. -55°</sup>C specifications are guaranteed by design.
7. Off-Channel Isolation = 20log10 (Vcom/Vno) (See Figure 6).



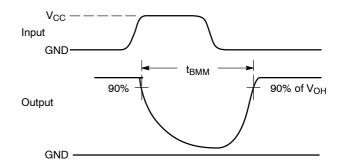
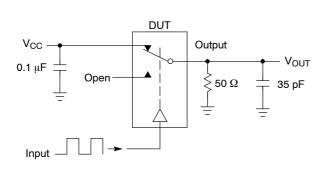


Figure 3. t<sub>BBM</sub> (Time Break-Before-Make)



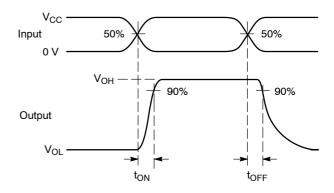
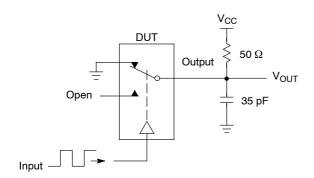


Figure 4. t<sub>ON</sub>/t<sub>OFF</sub>



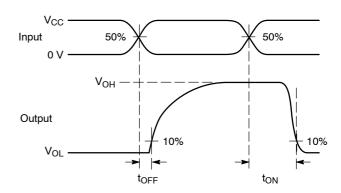
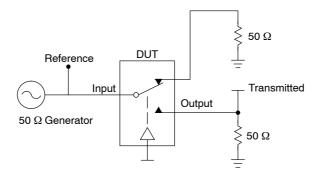


Figure 5.  $t_{ON}/t_{OFF}$ 



Channel switch control/s test socket is normalized. Off isolation is measured across an off channel. On loss is the bandwidth of an On switch.  $V_{\rm ISO}$ , Bandwidth and  $V_{\rm ONL}$  are independent of the input signal direction.

$$V_{ISO}$$
 = Off Channel Isolation = 20 Log  $\left(\frac{V_{OUT}}{V_{IN}}\right)$  for  $V_{IN}$  at 100 kHz

$$V_{ONL}$$
 = On Channel Loss = 20 Log  $\left(\frac{V_{OUT}}{V_{IN}}\right)$  for  $V_{IN}$  at 100 kHz to 50 MHz

Bandwidth (BW) = the frequency 3 dB below V<sub>ONL</sub>

 $V_{CT}$  = Use  $V_{ISO}$  setup and test to all other switch analog input/outputs terminated with 50  $\Omega$ 

Figure 6. Off Channel Isolation/On Channel Loss (BW)/Crosstalk (On Channel to Off Channel)/V<sub>ONL</sub>

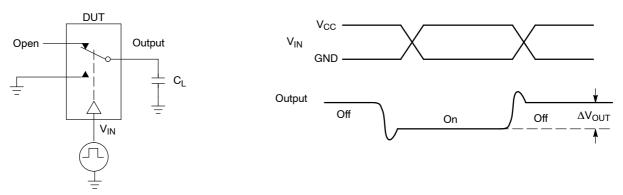


Figure 7. Charge Injection: (Q)

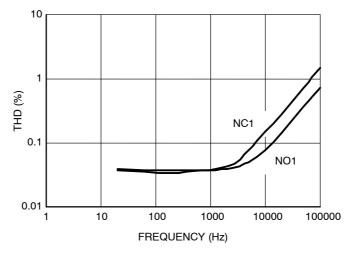
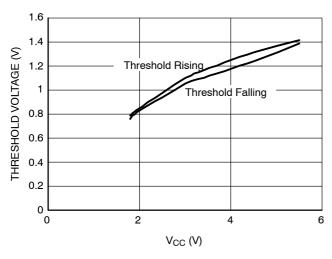


Figure 8. Total Harmonic Distortion Plus Noise Versus Frequency





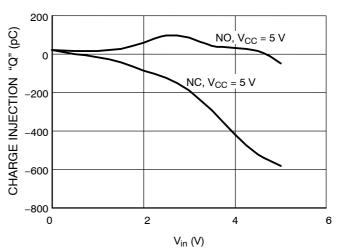


Figure 10. Charge Injection versus Vis

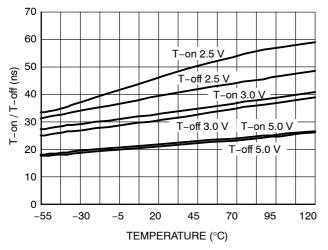


Figure 11. T-on / T-off Time versus Temperature

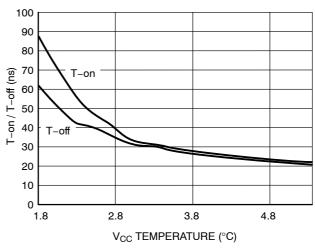


Figure 12. T-on / T-off Time versus Temperature

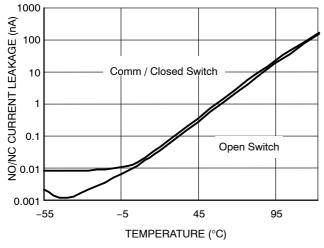


Figure 13. NO/NC Current Leakage Off and On,  $V_{CC}$  = 5 V

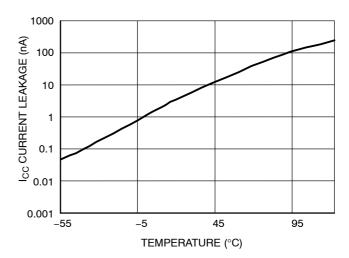


Figure 14. I<sub>CC</sub> Current Leakage versus Temperature V<sub>CC</sub> = 5.5 V

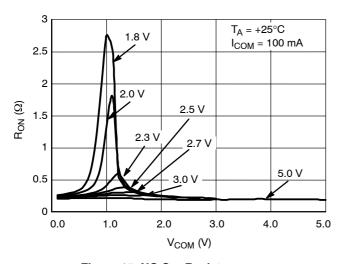


Figure 15. NC On-Resistance versus COM Voltage

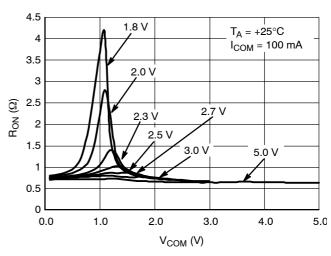


Figure 16. NO On-Resistance versus COM Voltage

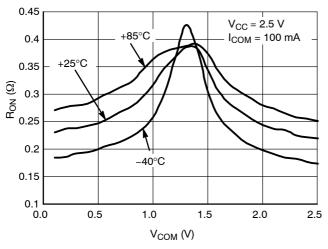


Figure 17. NC On-Resistance versus COM Voltage

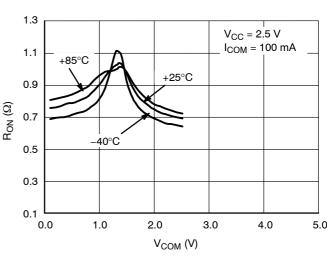


Figure 18. NO On-Resistance versus COM Voltage

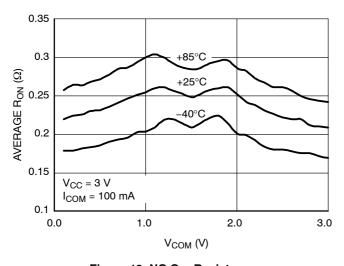


Figure 19. NC On-Resistance versus COM Voltage

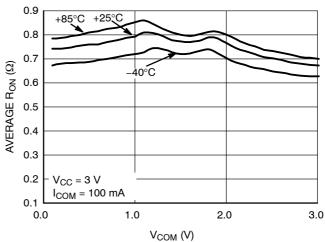


Figure 20. NC On-Resistance versus COM Voltage

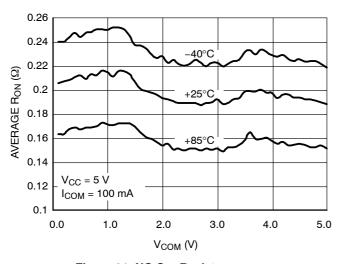


Figure 21. NC On-Resistance versus COM Voltage

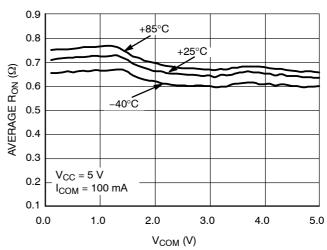


Figure 22. NO On-Resistance versus COM Voltage

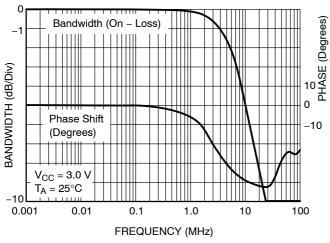


Figure 23. NC Bandwidth and Phase Shift versus Frequency

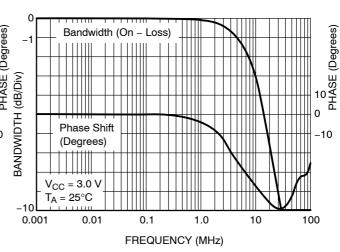


Figure 24. NO Bandwidth and Phase Shift versus Frequency

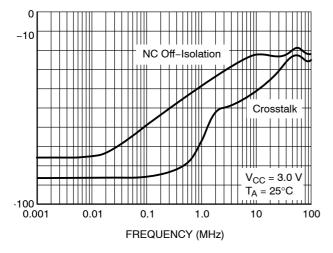


Figure 25. NC Off Isolation and Crosstalk

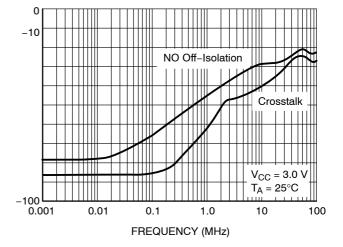
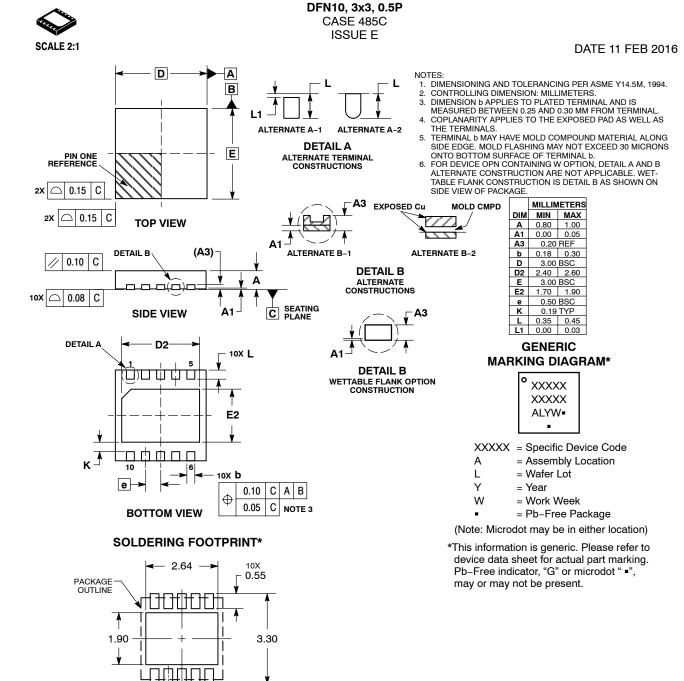


Figure 26. NO Off Isolation and Crosstalk

# **ORDERING INFORMATION**

Device	Package	Shipping†
NLAS4684FCT1	Microbump-10	3000 / Tape & Reel
NLAS4684FCT1G	Microbump-10 (Pb-Free)	3000 / Tape & Reel
NLAS4684FCTCG	Microbump-10 (Pb-Free)	3000 / Tape & Reel
NLAS4684MNR2	DFN10	3000 / Tape & Reel
NLAS4684MNR2G	DFN10 (Pb-Free)	3000 / Tape & Reel
NLAS4684MR2	Micro10	4000 / Tape & Reel
NLAS4684MR2G	Micro10 (Pb-Free)	4000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



DOCUMENT NUMBER:	98AON03161D	Electronic versions are uncontrolled except when accessed directly from the Document Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	DFN10, 3X3 MM, 0.5 MM P	ITCH	PAGE 1 OF 1		

10X 0.30

**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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0.50—



# 10 PIN FLIP-CHIP CASE 489AA-01



SCALE 4:1

**ISSUE A** 

**DATE 04 MAY 2004** 

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION:
- MILLIMETERS.
  COPLANARITY APPLIES TO SPHERICAL
  CROWNS OF SOLDER BALLS.

	MILLIMETERS			
DIM	MIN MAX			
Α		0.650		
A1	0.210	0.270		
A2	0.280 0.380			
D	1.965	BSC		
Е	1.465	BSC		
b	0.250	0.350		
е	0.500 BSC			
D1	1.500 BSC			
E1	1.000	BSC		

# **GENERIC MARKING DIAGRAM\***

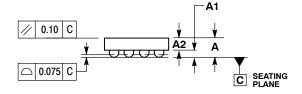


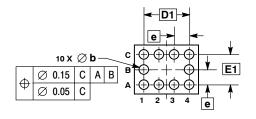
= Specific Device Code XXXX

YY = Year WW = Work Week

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

4 X		AB
△ 0.10 C	ا و	<b></b>
PIN ONE CORNER		





DOCUMENT NUMBER:	98AON12946D Electronic versions are uncontrolled except when accessed directly from the Document Reportant Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	10 PIN FLIP-CHIP		PAGE 1 OF 1

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Micro10 CASE 846B-03 ISSUE D

**DATE 07 DEC 2004** 

- NOTES:
  1. DIMENSIONING AND TOLERANCING PER
- DIMENSIONING AND TOLERANCING PER ANSI Y14-5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER. DIMENSION "A" DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

  4. DIMENSION "B" DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

  5. 846B-01 OBSOLETE. NEW STANDARD

  846B-02

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.114	0.122
В	2.90	3.10	0.114	0.122
С	0.95	1.10	0.037	0.043
D	0.20	0.30	0.008	0.012
G	0.50 BSC		0.020 BSC	
Н	0.05	0.15	0.002	0.006
J	0.10	0.21	0.004	0.008
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

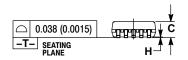
# **GENERIC MARKING DIAGRAM\***

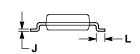


XXXX	= Device Code
Α	= Assembly Location
Υ	= Year
W	= Work Week
	= Pb-Free Package

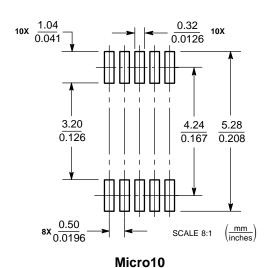
\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

# < -A- > D 8 PL PIN 1 ID ⊕ 0.08 (0.003) M T B S A S





# **SOLDERING FOOTPRINT**



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#### PAGE 2 OF 2

ISSUE	REVISION	DATE
0	RELEASED FOR PRODUCTION. REQ BY J. HOSKINS.	09 NOV 2000
Α	DIM "D" WAS 0.25-0.4MM/0.10-0.016IN. ADDED NOTE 5. USED ON: WAS 10 LEAD TSSOP, PITCH 0.65 REQ BY J. HOSKINS.	13 NOV 2000
В	CHANGED "USED ON" WAS: 10 LEAD TSSOP, PITCH 0.50MM. REQ BY A. HAMID.	11 JUL 2001
С	CHANGED "D" DIMENSION MAX FROM 0.35 TO 0.30MM AND 0.014 TO 0.012IN. REQ BY D. TRUHITTE.	31 JUL 2003
D	ADDED FOOTPRINT INFORMATION. REQ. BY K. OPPEN.	07 DEC 2004

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